

## NCE N-Channel Enhancement Mode Power MOSFET

## **Description**

The NCE3404 uses advanced trench technology to provide excellent  $R_{DS(ON)}$  and low gate charge. This device is suitable for use as a load switch and PWM applications.

#### **Genera Features**

•  $V_{DS} = 30V, I_D = 5.8A$ 

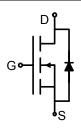
 $R_{DS(ON)}$  < 31m $\Omega$  @  $V_{GS}$ =10V

 $R_{DS(ON)}$  < 43m $\Omega$  @  $V_{GS}$ =4.5V

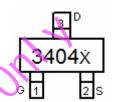
- High Power and current handing capability
- Lead free product is acquired
- Surface mount package

# **Application**

- Load switch
- ●PWM application



Schematic diagram



Marking and pin assignment



SOT-23 top view

## Package Marking and Ordering Information

	<u> </u>				
Device Marking	Device	Device Pack	age Reel Size	Tape width	Quantity
3404 X	NCE3404	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T<sub>A</sub>=25 ℃unless otherwise noted)

Parameter	Symbol	Limit	Unit	
Drain-Source Voltage	V <sub>DS</sub>	30	V	
Gate-Source Voltage	V <sub>GS</sub>	±20	V	
Drain Current-Continuous	I <sub>D</sub>	5.8	Α	
Drain Current-Pulsed (Note 1)	I <sub>DM</sub>	20	Α	
Maximum Power Dissipation	P <sub>D</sub>	1.4	W	
Operating Junction and Storage Temperature Range	$T_{J}$ , $T_{STG}$	-55 To 150	$^{\circ}$ C	

## **Thermal Characteristic**

Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ hetaJA}$	89	°C/W

### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	30	33	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =30V,V <sub>GS</sub> =0V	-	-	1	μΑ



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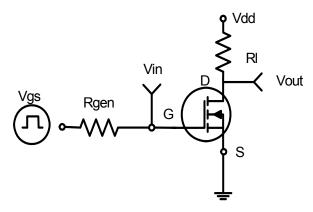
Parameter	Symbol	Condition	Min	Тур	Max	Unit
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics (Note 3)	<u> </u>		•			•
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250μA	1.2	1.6	2.4	V
Drain-Source On-State Resistance	В	V <sub>GS</sub> =10V, I <sub>D</sub> =5A	-	25.5	31	mΩ
Drain-Source On-State Resistance	$R_{DS(ON)}$	V <sub>GS</sub> =4.5V, I <sub>D</sub> =4A	-	36	43	mΩ
Forward Transconductance	<b>g</b> fs	V <sub>DS</sub> =5V,I <sub>D</sub> =5A	-	15	-	S
Dynamic Characteristics (Note4)	<u>.</u>		•			
Input Capacitance	C <sub>lss</sub>	\/ -15\/\/ -0\/	-	485.8	-	PF
Output Capacitance	Coss	$V_{DS}$ =15V, $V_{GS}$ =0V, F=1.0MHz	_	65.2	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0WHZ	4	54	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	5	-	nS
Turn-on Rise Time	t <sub>r</sub>	$V_{DD}$ =15V, $R_L$ =3 $\Omega$	-	3	-	nS
Turn-Off Delay Time	$t_{d(off)}$	$V_{GS}$ =10 $V_{R_{GEN}}$ =3 $\Omega$	-	15	-	nS
Turn-Off Fall Time	t <sub>f</sub>	115	-	3.5	-	nS
Total Gate Charge	Qg	V <sub>DS</sub> =15V,I <sub>D</sub> =6A, V <sub>GS</sub> =10V	-	12.6	-	nC
Gate-Source Charge	$Q_{gs}$		-	1.9	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> -10V	-	2.6	-	nC
Drain-Source Diode Characteristics	1111	•				
Diode Forward Voltage (Note 3)	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>S</sub> =6A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	5.8	Α

#### Notes:

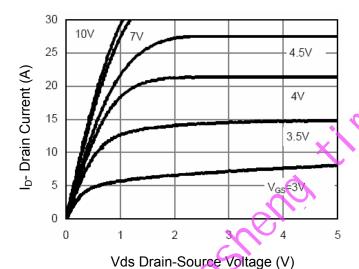
- $\textbf{1.} \ \textbf{Repetitive Rating: Pulse width limited by maximum junction temperature}.$
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- **3.** Pulse Test: Pulse Width ≤  $300\mu$ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production



# **Typical Electrical and Thermal Characteristics**



**Figure 1:Switching Test Circuit** 



**Figure 3 Output Characteristics** 

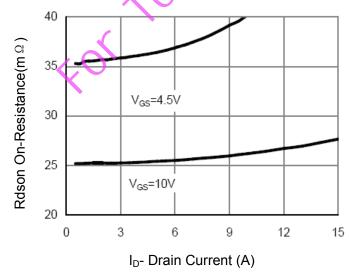


Figure 5 Drain-Source On-Resistance

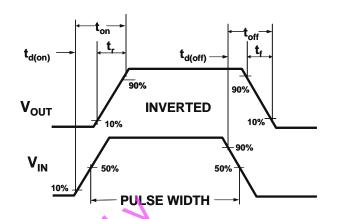
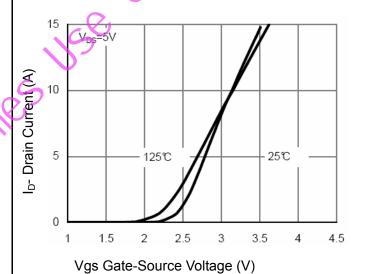


Figure 2:Switching Waveforms



**Figure 4 Transfer Characteristics** 

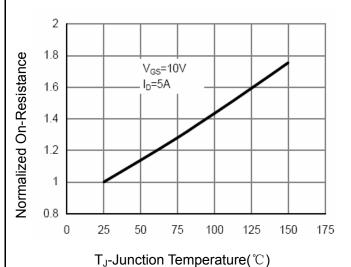
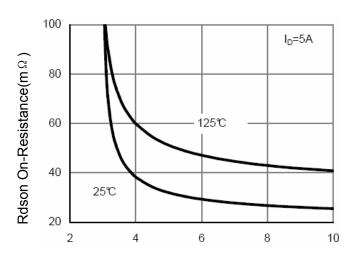


Figure 6 Drain-Source On-Resistance





Vgs Gate-Source Voltage (V)



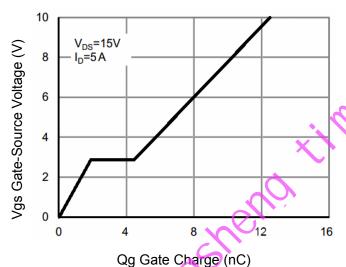


Figure 9 Gate Charge

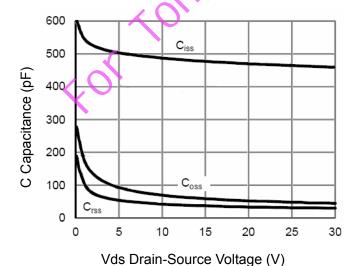
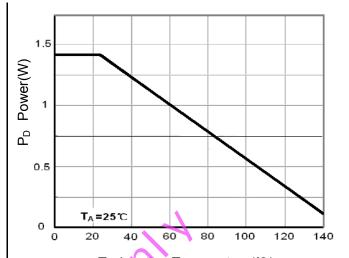


Figure 11 Capacitance vs Vds



T<sub>J</sub>-Junction Temperature(°C) Figure 8 Power Dissipation

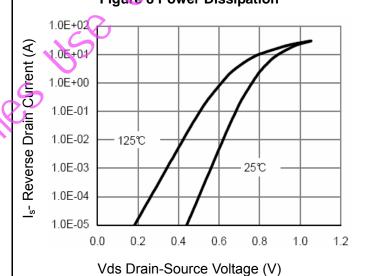
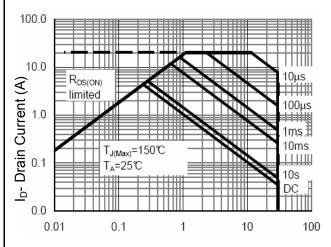


Figure 10 Source- Drain Diode Forward



Vds Drain-Source Voltage (V)

Figure 12 Safe Operation Area



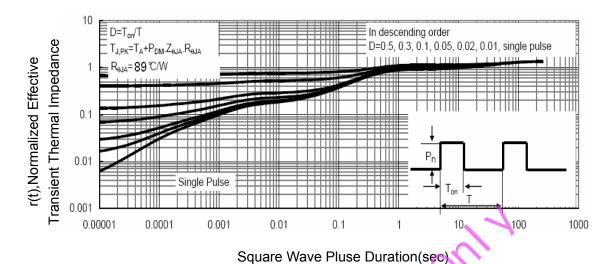
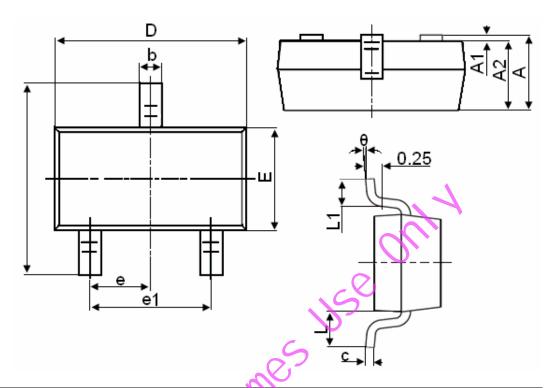


Figure 13 Normalized Maximum Transient Thermal Impedance

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# **SOT-23 Package Information**



Symbol	Dimensions in Millimeters			
Symbol	MIN.	MAX.		
А	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
С	0.080	0.150		
D	2.800	3.000		
E	1.200	1.400		
E1	2.250	2.550		
е	0.950TYP			
e1	1.800	2.000		
L	0.550REF			
L1	0.300	0.500		
θ	0°	8°		

### **Notes**

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- $5. \ Controlling \ dimension \ is \ millimeter, \ converted \ inch \ dimensions \ are \ not \ necessarily \ exact.$



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